Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S4	644	372/38.02.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:49
S6	388	372/38.02.ccls. and (resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:50
S7	108	372/38.02.ccls. and (inductor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:50
S9	193	S5 and S6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:51
S10	53	S5 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:51
S11	5	S5 and S8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:51
S12	2	S5 and S8 and S9 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:51
S5	270	372/38.02.ccls. and (bias adj3 current)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:52

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S13	47519	(bias adj3 current)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:52
S8	26	372/38.02.ccls. and (thin adj3 film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:53
S15	299	S13 and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:53
S16	264	S13 and S14 and parallel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:53
S14	4031	(resistor and inductor) and (thin adj3 film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 09:55
S18	53	(resistor and inductor) adj3 (thin adj3 film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 10:34
S19	4	S13 and ((resistor and inductor) adj3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 10:34
S17	156	(resistor and inductor) near3 (thin adj3 film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 10:37

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520	11	S13 and ((resistor and inductor) near3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 11:30
S21	1	331/66,40,108.ccls. and ((resistor and inductor) near3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 11:31
S22	2	333/174,172,185.ccls. and ((resistor and inductor) near3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:07
S23	11	KYOCERA and ((resistor and inductor) near3 (thin adj3 film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:08
S24	2	KYOCERA and ((resistor and inductor) near3 (thin adj3 film)) and (bias adj3 current)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 12:09
S3	2	("2002374028").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/08 09:20
S25	1	driver and ((first and second) near3 (insulation adj3 plate)) and (coupl\$4) and (bias adj3 current)	US-PGPUB	OR	ON	2006/09/08 09:22
S26	1	driver and ((first and second) near3 (insulation adj3 plate)) and (coupl\$4) and (bias adj3 current) and (thin adj3 film) and inductor and resistor	US-PGPUB	OR	ON	2006/09/08 09:23
S27	1	((first and second) near3 (insulation adj3 plate)) and (bias adj3 current) and (thin adj3 film) and inductor and resistor	US-PGPUB	OR	ON	2006/09/08 09:23
S28	1	((first and second) near3 (insulation adj3 plate)) and (thin adj3 film) and inductor and resistor	US-PGPUB	OR	ON	2006/09/08 09:25

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S29	4	((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor)	US-PGPUB	OR	ON	2006/09/08 09:26
S30	2	((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and (bias adj3 current)	US-PGPUB	OR	ON	2006/09/08 09:27
S31	224	372/38.02.ccls.	US-PGPUB	OR	ON	2006/09/08 09:29
S32	679	372/38.02.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:33
S33	0	372/38.01.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:35
S34	273	372/38.01.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:40
S35	249	372/38.1.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:43
S36	1	372/38.1-38.09.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/09/08 09:44
S37	1	"372"/\$\$\$.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:44

S38	2	333/174.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:44
S39	2	333/172.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:45
S40	2	333/185.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:47
S42	2	((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel	US-PGPUB	OR	ON	2006/09/08 09:47
S41	2	"333"/\$\$\$.ccls. and (((first and second) near3 insulation) and ((thin adj3 film) near4 inductor and resistor) and parallel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/08 09:48